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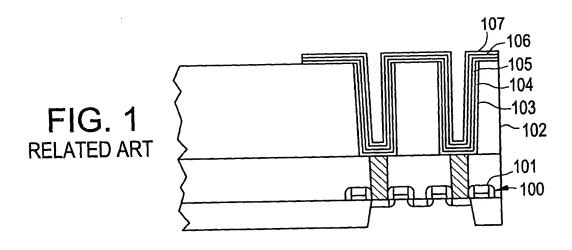
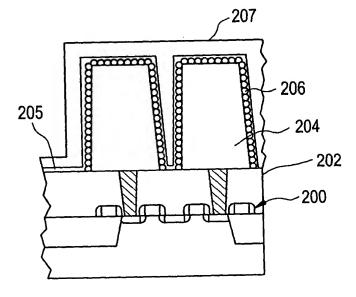
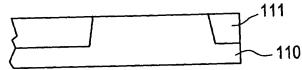


FIG. 2 **RELATED ART**









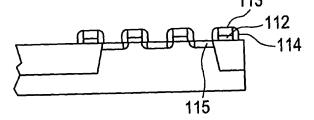


FIG. 3C **RELATED ART**

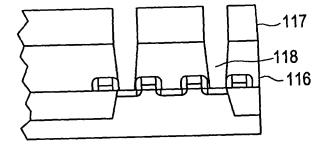
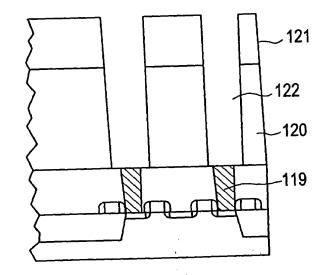


FIG. 3D **RELATED ART**



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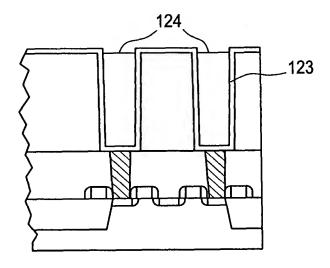


FIG. 3F RELATED ART

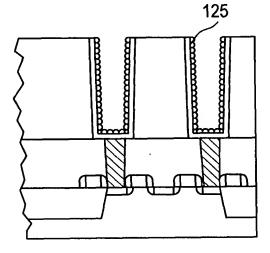


FIG. 3G RELATED ART

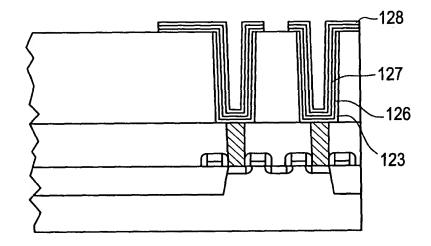
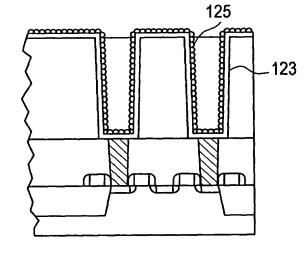


FIG. 4 PRIOR ART



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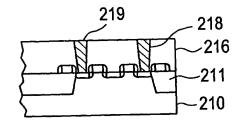


FIG. 5B RELATED ART

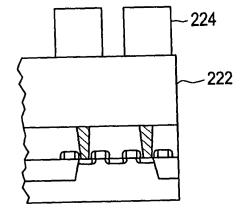


FIG. 5C RELATED ART

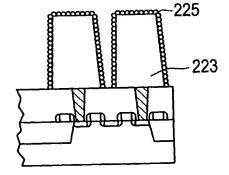
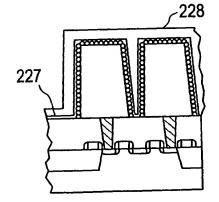


FIG. 5D RELATED ART



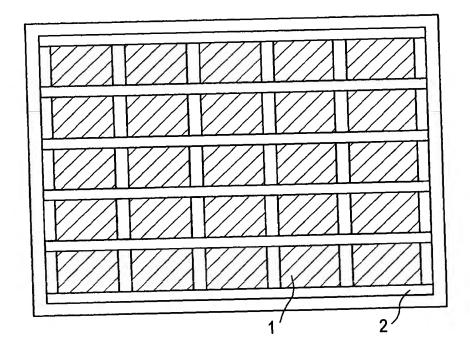
COGIVETA CESOL

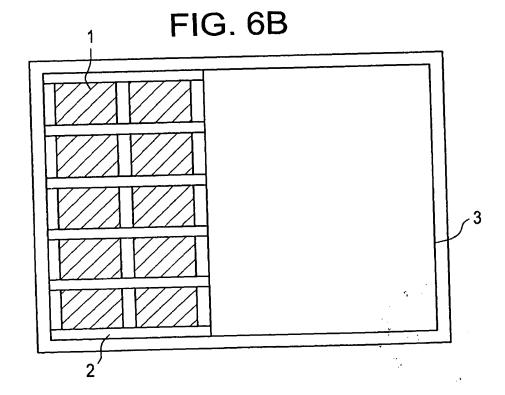
PRAFTSMAN

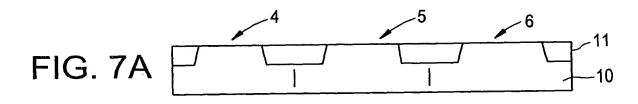
OTO et al.; Appln. No. 09/817,233; Conf. No.:
'Manufacts of Method of Semiconductor Device Having DRANT Capacitors'

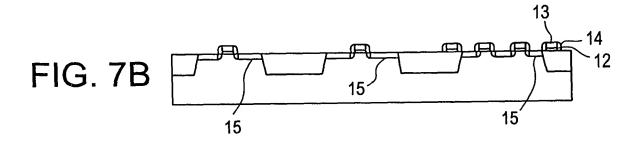
6/8

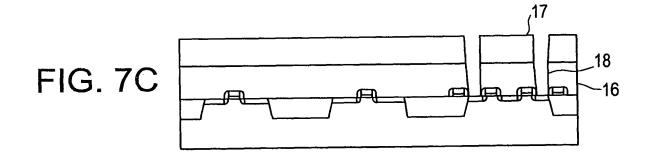
FIG. 6A RELATED ART

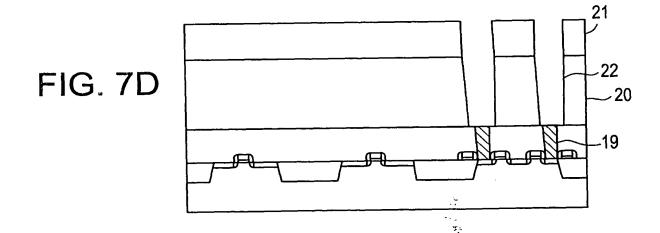














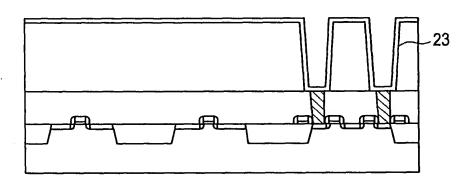


FIG. 7F

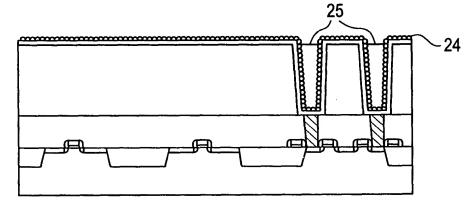


FIG. 7G

